

- MN25 Lecture 4
- ⊖ Reduced Models provide geometrical insight into neuronal response to stimulation.
  - ⊖ Reductions must be handled carefully;  
Bifurcation diagrams may really differ.
  - ⊖ Additional currents modulating the subthreshold dynamics

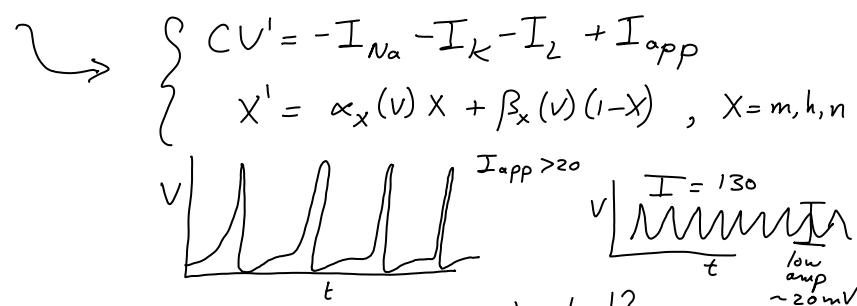
Recall

- ⊖ Approach: phase plane analysis of switched systems.

Week 1: Hodgkin-Huxley 4D model

Week 2: Phase planes

Week 3: Codim 1 bifurcations.



Q: What is an action potential?

Reaching a threshold is somewhat too arbitrary.  
Mathematically, an oscillation is well defined.

Q: 4D is difficult, let's reduce to a planar model.

Approach ①: Note that  $\tau_m(V) = \frac{1}{\alpha + \beta}$  is small, order 0.1-0.5 ms, so just as fast as the potential  $V$ .

So set  $m = m_\infty(V)$  Reduction by 1 variable.

The figure suggests  $n = b_0 - r h \Rightarrow$  This reduces it to a 2D system.

Set  $b_0 = 0.8$   $r = 0.9$  bad choice  
 $r = 1.0$  good choice.

We observe that for  $r=1.0$  we have a qualitatively similar bifurcation diagram (sufficiently) as for the original HH model.

Approach ② How could we even compare variables that have different units?  
Equivalent Potentials to convert  $m, h, n$  to  $V_m, V_h, V_n$

Observation  $X_\infty(V) = \frac{\alpha}{\alpha + \beta}$  are monotone functions

So we can invert this function  
but we will do this only implicitly.

$$X(t) = X_\infty(V_x(t)) \xrightarrow{d/dt} X' = \frac{dX_\infty}{dV_x} \frac{dV_x}{dt} = \frac{X_\infty(V) - X}{\tau_x(V)}$$

↑ equivalent potential for  $X=m, h, n$

$$\text{So we have } \frac{dV_x}{dt} = \frac{X_\infty(V) - X_\infty(V_x)}{\tau_x(V)} / \left( \frac{dX_\infty(V_x)}{dV_x} \right)$$

From the timeseries we see  $V_m$  follows  $V$  closely  
and  $V_n$  &  $V_h$  evolve at the same timescale.

We obtain a 2D model by setting  
 $V_m \rightarrow V$   
 $V_n \rightarrow V_h$

Continuing with a zoo of currents. (So sorry we're not closer to artis today.)

### § 4.1 on conductance-based models

Most neuron models have one mechanism/current responsible  
for the shape of the action potential  
 $\text{Na}^+$  in HH //  $\text{Ca}^{2+}$  for ML.

$$I_{\text{ion}} = \bar{g} m^P h^Q I_{\text{drive}}(V, \text{ions})$$

$$I_{\text{Ca}} = P_{\max} \bar{g} F \left( \frac{C_{\text{in}} - C_{\text{out}} e^{-\xi}}{1 - e^{-\xi}} \right) \approx \bar{g}(V - E_{\text{rev}})$$

↑ if ion concentration  
almost constant.

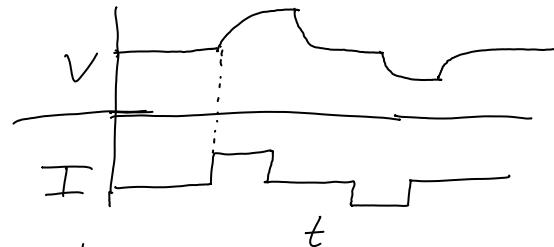
### § 4.2 T-type Calcium Current

Model without  $\text{Na}^+, \text{K}^+$  (consider them blocked) Is ok as that mostly  
shapes the spike.

$$\left\{ \begin{array}{l} CV' = I_{\text{app}} - g_L(V - E_L) - I_T \\ \frac{dh}{dt} = (h_\infty(V) - h)/\tau(V) \end{array} \right.$$

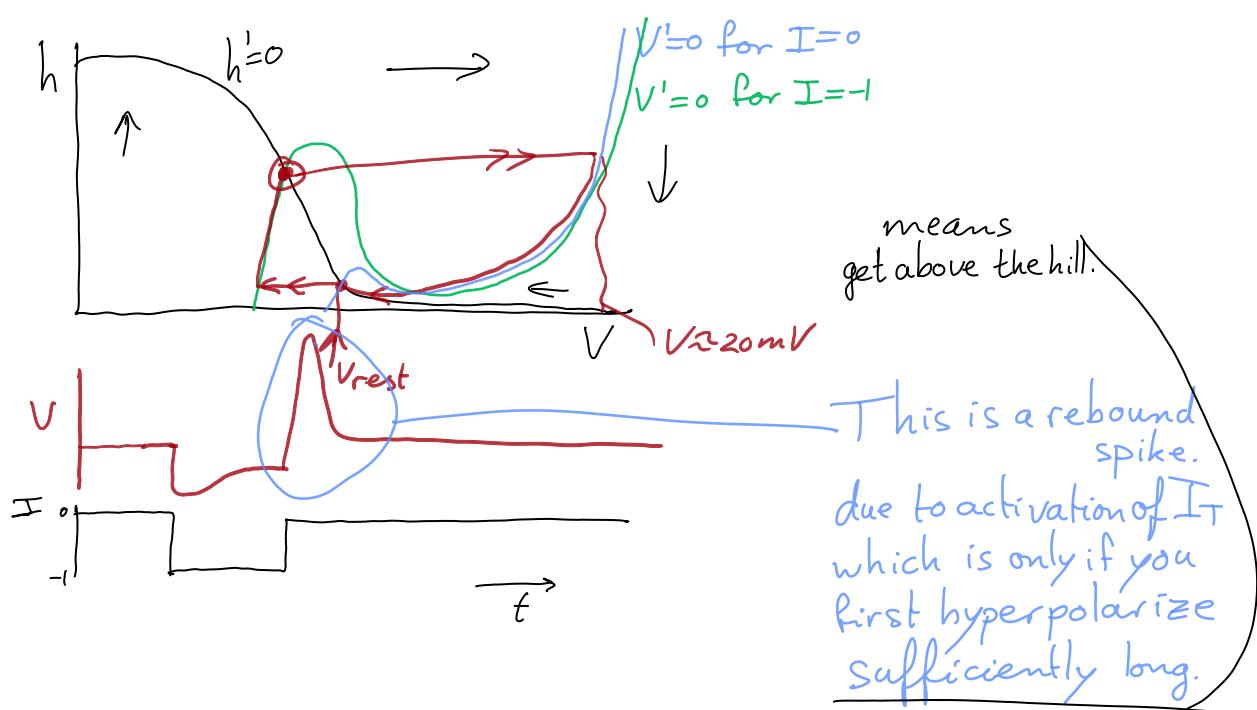
$$\frac{dh}{dt} = (h_\infty(V) - h)/\tau(V) \quad \leftarrow \text{slow inactivation.}$$

$$I_T = m_\infty^2 h I_{\text{Ca}}(V, \text{Ca}_o, \text{Ca}_i)$$



- ① Relay mode near  $V_{\text{rest}} \approx -60 \text{ mV}$   
passive response to  $I_{\text{app}}$

- ② For larger inhibitory input, the model has  
a rebound mode.



## § 4.5 Sag Current (Resilience)

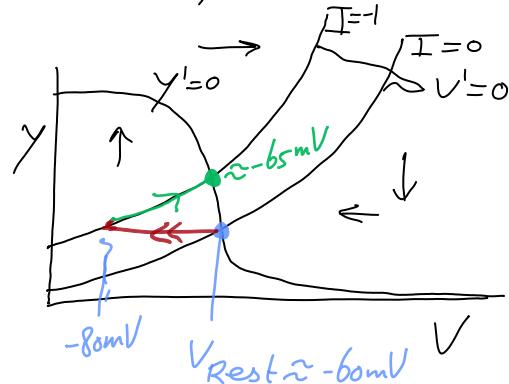
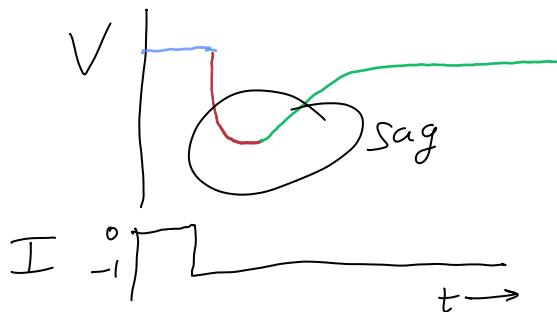
activates upon hyperpolarized.

$$CV' = I(t) - g_L(V - E_L) - g_h y(V - E_h)$$

$$y' = (y_\infty(t) - y)/\tau_y(V) \leftarrow \text{again slow.}$$

$E_h \approx -43 \text{ mV}$   
mix of  $\text{Na}^+$  &  $\text{K}^+$

$\rightarrow \tau_y$  is large.

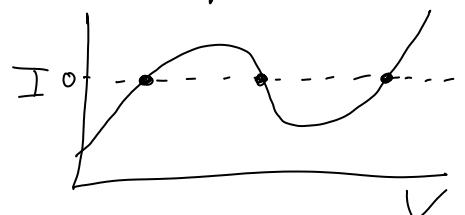
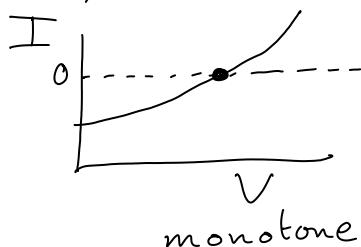


## § 4.4.3 Potassium (K) Inward Rectifier

During Patch-clamp, experimentalist fix  $V$  to hold the potential at some value.

$$CV' = -I_{\text{ion}}(V) + I_{\text{app}} = 0$$

They can measure the IV-curve of a neuron. (s.t.  $V'=0$ )



A model for non-monotone IV curves

$$CV' = I - g_L(V - E_L) - g_{K_{ir}} h_\infty(V)(V - E_K)$$

$I_{K_{ir}}$  provides additional repolarization.  
(more negative)

$$\text{Set } V'=0 \Rightarrow I = g_L(V - E_L) + g_{K_{ir}} h_\infty(V)(V - E_K)$$

$$\frac{dI}{dV} = \underbrace{g_L + g_{K_{ir}} h_\infty}_{\text{positive}} + \underbrace{g_{K_{ir}} h'_\infty(V - E_K)}_{h' < 0, \text{ could be dominant.}}$$

## § 4.4.2 M-current Slow potassium current

gate M increases whenever there is a spike.

$$\left\{ \begin{array}{l} CV' = -I_{\text{ion}} + I_{\text{app}} - g_M M(V - E_K) \\ M' = (M_\infty - M)/\tau_M \end{array} \right.$$

Increases whenever there is a spike.  
Making it harder to generate the next.



